

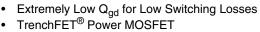


N-Channel Reduced Q_g, Fast Switching MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)		
30	0.00975 at V _{GS} = 10 V	15		
	0.01375 at V _{GS} = 4.5 V	13		

FEATURES

Halogen-free According to IEC 61249-2-21



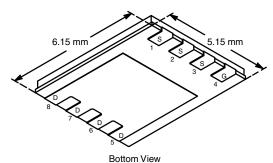
- New Low Thermal Resistance PowerPAK® Package with Low 1.07 mm Profile



- 100 % UIS Tested
- Complaint to RoHS Directive 2002/95/EC



PowerPAK SO-8

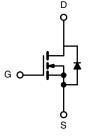


Ordering Information: Si7392DP-T1-E3 (Lead (Pb)-free)

Si7392DP-T1-GE3 (Lead (Pb)-free and Halogen-free)

APPLICATIONS

- High-Side DC/DC Conversion
 - Notebook
 - Server



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unle	ess otherwise i	noted)			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	30		V	
Gate-Source Voltage		V _{GS}	=			
Continuous Dusin Current /T 150 °C\8	T _A = 25 °C	I _D	15	9		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		12	7		
Pulsed Drain Current		I _{DM}	± 50		Α	
Continuous Source Current (Diode Conduction) ^a		I _S	4.1	1.5		
Avalanche Current	L = 0.1 mH	I _{AS}	30			
Single-Pulse Avalanche Energy	L=0.1 mn	E _{AS}	45		mJ	
	T _A = 25 °C	C	5	1.8	W	
Maximum Power Dissipation ^a	T _A = 70 °C	P _D	3.2	1.1	VV	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150			
Soldering Recommendations (Peak Temperature) ^{b, c}			260		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manipular Institut In Applicat (MOOFFT)	t ≤ 10 s	R _{thJA}	20	25	°C/W
Maximum Junction-to-Ambient (MOSFET) ^a	Steady State		53	70	
Maximum Junction-to-Case (Drain)	Steady State	R_{thJC}	3.5	4.5	

- a. Surface mounted on 1" x 1" FR4 board.
- b. See solder profile (www.vishay.com/ppg?73257). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.
- * Pb containing terminations are not RoHS compliant, exemptions may apply.

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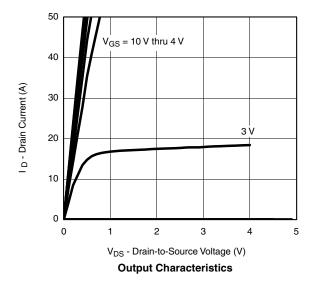
MOSFET SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0		3.0	٧		
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA		
Zava Cata Valtaga Dvain Current	,	V _{DS} = 30 V, V _{GS} = 0 V			1			
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			5	μΑ		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α		
	D	V _{GS} = 10 V, I _D = 15 A		0.008	0.00975			
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 13 A		0.011	0.01375	Ω		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 15 A		40		S		
Diode Forward Voltage ^a	V_{SD}	I _S = 4.1 A, V _{GS} = 0 V		0.75	1.1	V		
Dynamic ^b								
Total Gate Charge	Q_g			10	15			
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 15 \text{ A}$		3.5		nC		
Gate-Drain Charge	Q_{gd}			2.6				
Gate Resistance	R_g			1.6	2.7	Ω		
Turn-On Delay Time	t _{d(on)}			15	25			
Rise Time	t _r	V_{DD} = 15 V, R_L = 15 Ω		7	15			
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		46	70	ns		
Fall Time	t _f			9	17			
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 2.7 A, dI/dt = 100 A/μs		30	60			

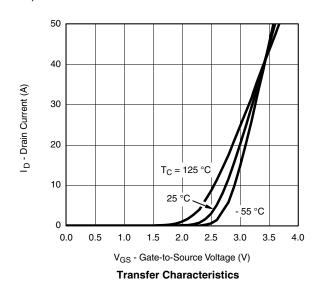
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

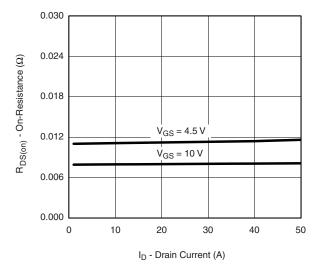




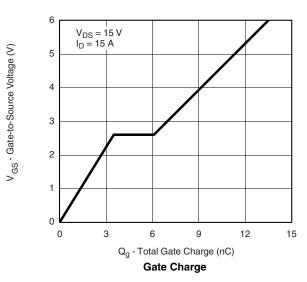


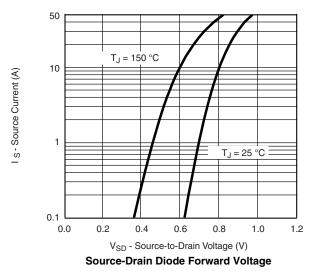


TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



On-Resistance vs. Drain Current

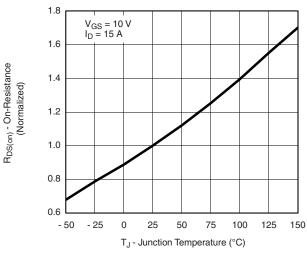




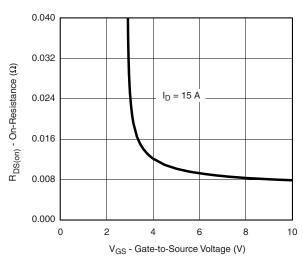
1800
1500
C_{iss}
1200
900
C_{oss}
0
0
600
12
18
24
30

V_{DS} - Drain-to-Source Voltage (V)

Capacitance



On-Resistance vs. Junction Temperature

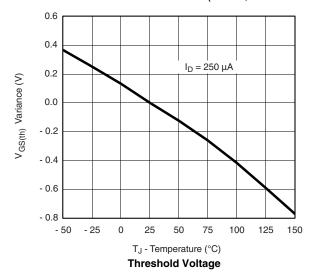


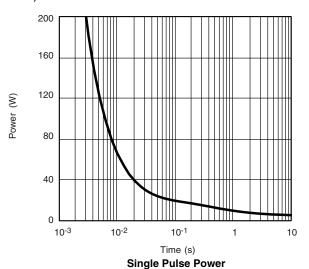
On-Resistance vs. Gate-to-Source Voltage

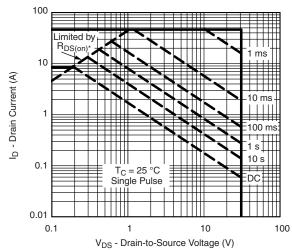
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

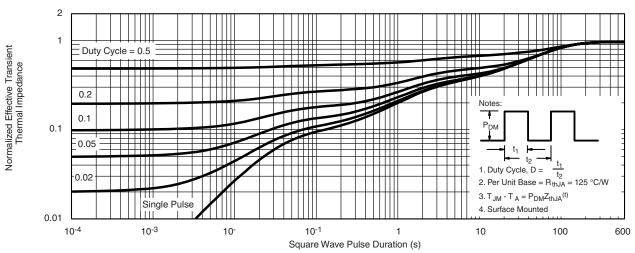






 * V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

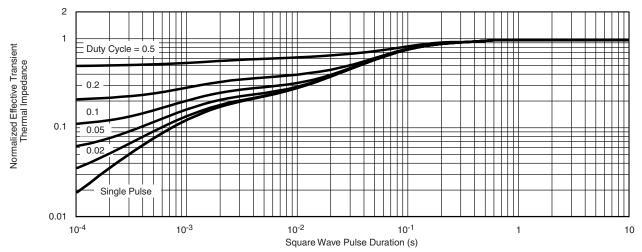
Safe Operating Area, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

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